

## SD101A - SD101C

### FEATURES :

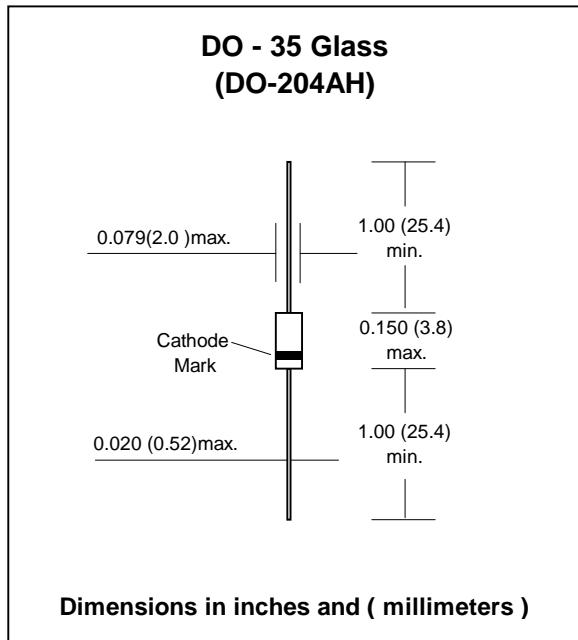
- For general purpose applications
- The LL101 series is a metal-on-silicon Schottky barrier device which is protected by a PN junction guard ring.
- The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing and coupling diodes for fast switching and low logic level applications.
- These diodes are also available in the MiniMELF case with type designations LL101A thru LL101C.
- Pb / RoHS Free

### MECHANICAL DATA :

**Case:** DO-35 Glass Case

**Weight:** approx. 0.13g

## SCHOTTKY BARRIER DIODES



### Maximum Ratings and Thermal Characteristics (Rating at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	60	V
SD101A		50	
SD101B		40	
SD101C			
Maximum Single Cycle Surge 10ms Square Wave	$I_{FSM}$	2	A
Power Dissipation (Infinite Heatsink)	$P_D$	400 <sup>(1)</sup>	mW
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	0.3 <sup>(1)</sup>	°C/mW
Junction Temperature	$T_J$	125 <sup>(1)</sup>	°C
Storage temperature range	$T_S$	-55 to + 150 <sup>(1)</sup>	°C

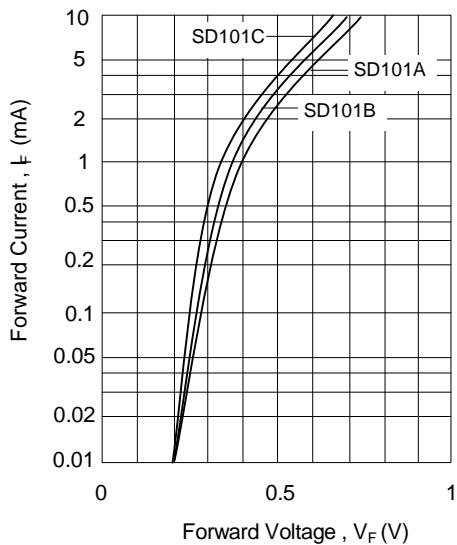
Note: (1) Valid provided that leads at a distance of 4mm from case are kept at ambient temperature.

### Electrical Characteristics ( $T_J = 25^\circ C$ unless otherwise noted)

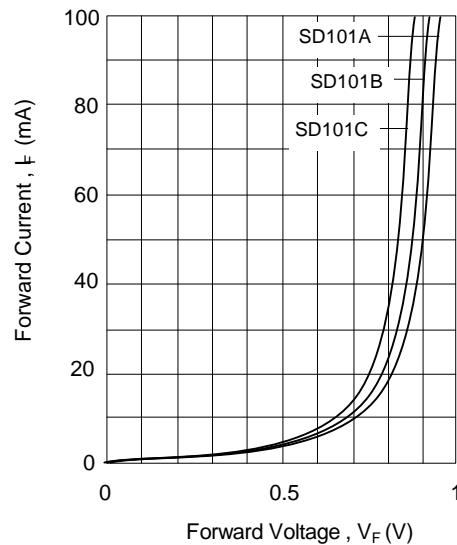
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Breakdown Voltage	$V_{(BR)R}$	$I_R = 10 \mu A$	60	-	-	V
SD101A			50	-	-	
SD101B			40	-	-	
SD101C						
Reverse Current	$I_R$	$V_R = 50 V$ $V_R = 40 V$ $V_R = 30 V$	-	-	200	nA
SD101A			-	-	200	
SD101B			-	-	200	
SD101C			-	-	200	
Forward Voltage Drop	$V_F$	$I_F = 1mA$  $I_F = 15mA$	-	-	0.41	V
SD101A			-	-	0.4	
SD101B			-	-	0.39	
SD101C			-	-	1.0	
SD101A			-	-	0.95	
SD101B			-	-	0.9	
SD101C			-	-		
Reverse Recovery Time	$T_{rr}$	$I_F = I_R = 5mA$ , recover to $0.1I_R$	-	-	1	ns

## RATING AND CHARACTERISTIC CURVES ( SD101A - SD101C )

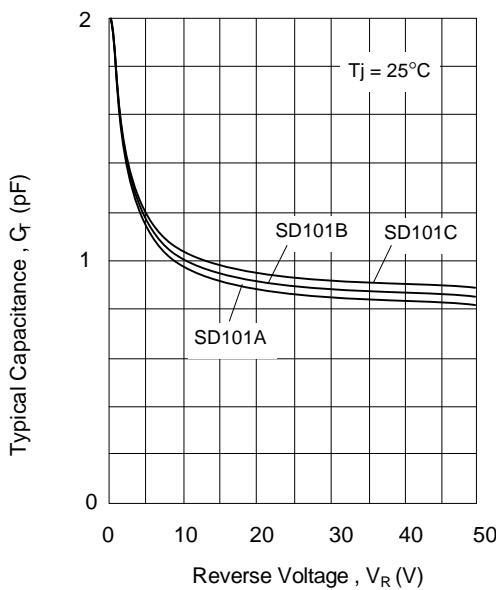
**Typical variation of forward current and forward voltage for primary conduction through the schottky barrier**



**Typical forward conduction curve of combination Schottky barrier and PN junction guard ring**



**Typical capacitance curve as a function of reverse Voltage**



**Typical variation of reverse current at various temperatures**

